NSN 5961-01-131-2102

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-131-2102 **Inclosure Material:** Metal **Overall Length:** 1.272 inches **Overall Height:** 0.347 inches **Overall Width:** 0.717 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 collector to emitter voltage, dc with specified circuit between base and emitter and 400.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 7.00 amperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No